## 2N5550, 2N5551

## Preferred Device

## Amplifier Transistors

NPN Silicon

## Features

- These are $\mathrm{Pb}-$ Free Devices*


## MAXIMUM RATINGS



## THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
| :---: | :---: | :---: | :---: |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta J A}$ | 200 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| Thermal Resistance, Junction-to-Case | $\mathrm{R}_{\theta \mathrm{JC}}$ | 83.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.


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MARKING DIAGRAM


$$
\begin{array}{ll}
\mathrm{X} & =0 \text { or } 1 \\
\mathrm{~A} & =\text { Assembly Location } \\
\mathrm{Y} & =\text { Year } \\
\text { WW } & =\text { Work Week } \\
\text { - } & =\text { Pb-Free Package }
\end{array}
$$

(Note: Microdot may be in either location)

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted)

| Characteristic |  | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| OFF CHARACTERISTICS |  |  |  |  |  |
| Collector-Emitter Breakdown Voltage (Note 1) $\left(I_{C}=1.0 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0\right)$ | $\begin{aligned} & \text { 2N5550 } \\ & \text { 2N5551 } \end{aligned}$ | $\mathrm{V}_{\text {(BR)CEO }}$ | $\begin{aligned} & 140 \\ & 160 \end{aligned}$ | - | Vdc |
| Collector-Base Breakdown Voltage $\left(\mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{E}}=0\right)$ | $\begin{aligned} & \text { 2N5550 } \\ & \text { 2N5551 } \end{aligned}$ | $\mathrm{V}_{\text {(BR) }} \mathrm{CBO}$ | $\begin{aligned} & 160 \\ & 180 \end{aligned}$ | - | Vdc |
| Emitter-Base Breakdown Voltage $\left(I_{E}=10 \mu \mathrm{Adc}, \mathrm{I}_{\mathrm{C}}=0\right)$ |  | $\mathrm{V}_{\text {(BR) }{ }^{\text {EBO }}}$ | 6.0 | - | Vdc |
| $\begin{aligned} & \text { Collector Cutoff Current } \\ & \left(V_{C B}=100 \mathrm{Vdc}, I_{E}=0\right) \\ & \left(V_{C B}=120 \mathrm{Vdc}, I_{E}=0\right) \\ & \left(\mathrm{V}_{\mathrm{CB}}=100 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, T_{\mathrm{A}}=100^{\circ} \mathrm{C}\right) \\ & \left(\mathrm{V}_{\mathrm{CB}}=120 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{~T}_{\mathrm{A}}=100^{\circ} \mathrm{C}\right) \end{aligned}$ | $\begin{aligned} & \text { 2N5550 } \\ & \text { 2N5551 } \\ & \text { 2N5550 } \\ & \text { 2N5551 } \end{aligned}$ | $\mathrm{I}_{\text {cbo }}$ | - | $\begin{gathered} 100 \\ 50 \\ 100 \\ 50 \end{gathered}$ | nAdc <br> $\mu \mathrm{Adc}$ |
| Emitter Cutoff Current $\left(\mathrm{V}_{\mathrm{EB}}=4.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0\right)$ |  | ${ }_{\text {E }}$ bo | - | 50 | nAdc |

ON CHARACTERISTICS (Note 1)

| $\begin{aligned} & \text { DC Current Gain } \\ & \text { ( } \left.\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=50 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}\right) \end{aligned}$ | 2N5550 2N5551 2N5550 2N5551 2N5550 2N5551 | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 60 \\ & 80 \\ & 60 \\ & 80 \\ & 20 \\ & 30 \end{aligned}$ | $\begin{gathered} - \\ - \\ 250 \\ 250 \\ - \\ - \end{gathered}$ | - |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Collector-Emitter Saturation Voltage $\left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=1.0 \mathrm{mAdc}\right)$ $\left(I_{C}=50 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=5.0 \mathrm{mAdc}\right)$ | $\begin{array}{r} \text { Both Types } \\ \text { 2N5550 } \\ \text { 2N5551 } \end{array}$ | $\mathrm{V}_{\text {CE(sat) }}$ | - | $\begin{aligned} & 0.15 \\ & 0.25 \\ & 0.20 \end{aligned}$ | Vdc |
| Base-Emitter Saturation Voltage $\left(I_{C}=10 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=1.0 \mathrm{mAdc}\right)$ $\left(I_{C}=50 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=5.0 \mathrm{mAdc}\right)$ | $\begin{array}{r} \text { Both Types } \\ \text { 2N5550 } \\ \text { 2N5551 } \end{array}$ | $V_{B E \text { (sat) }}$ | - | $\begin{aligned} & 1.0 \\ & 1.2 \\ & 1.0 \end{aligned}$ | Vdc |

SMALL-SIGNAL CHARACTERISTICS

| $\begin{aligned} & \text { Current-Gain - Bandwidth Product } \\ & \qquad\left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{mAdc}, \mathrm{~V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}=100 \mathrm{MHz}\right) \end{aligned}$ |  | $\mathrm{f}_{\text {T }}$ | 100 | 300 | MHz |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Output Capacitance $\left(\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ |  | $\mathrm{C}_{\text {obo }}$ | - | 6.0 | pF |
| Input Capacitance $\left(\mathrm{V}_{\mathrm{EB}}=0.5 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | $\begin{aligned} & \text { 2N5550 } \\ & \text { 2N5551 } \end{aligned}$ | $\mathrm{C}_{\text {ibo }}$ | - | $\begin{aligned} & 30 \\ & 20 \end{aligned}$ | pF |
| Small-Signal Current Gain $\left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{mAdc}, \mathrm{V}_{\mathrm{CE}}=10 \mathrm{Vdc}, \mathrm{f}=1.0 \mathrm{kHz}\right)$ |  | $\mathrm{hf}_{\text {fe }}$ | 50 | 200 | - |
| Noise Figure $\left(\mathrm{I}_{\mathrm{C}}=250 \mu \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=5.0 \mathrm{Vdc}, \mathrm{R}_{\mathrm{S}}=1.0 \mathrm{k} \Omega, \mathrm{f}=1.0 \mathrm{kHz}\right)$ | $\begin{aligned} & \text { 2N5550 } \\ & \text { 2N5551 } \end{aligned}$ | NF | - | $\begin{aligned} & 10 \\ & 8.0 \end{aligned}$ | dB |

1. Pulse Test: Pulse Width $\leq 300 \mu$ s, Duty Cycle $\leq 2.0 \%$.


Figure 1. DC Current Gain


Figure 2. Collector Saturation Region


Figure 3. Collector Cut-Off Region


Figure 4. "On" Voltages


Figure 5. Temperature Coefficients


Values Shown are for $\mathrm{I}_{\mathrm{C}} @ 10 \mathrm{~mA}$

Figure 6. Switching Time Test Circuit


Figure 8. Turn-On Time


Figure 7. Capacitances


Figure 9. Turn-Off Time

## 2N5550, 2N5551

ORDERING INFORMATION

| Device | Package | Shipping ${ }^{\dagger}$ |
| :---: | :---: | :---: |
| 2N5550G | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ | 5000 Units / Bulk |
| 2N5550RLRPG | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ | 2000 / Tape \& Ammo Box |
| 2N5551G | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ | 5000 Units / Bulk |
| 2N5551RL1G | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ | 2000 / Tape \& Reel |
| 2N5551RLRAG | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ |  |
| 2N5551RLRPG | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ | 2000 / Tape \& Ammo Box |
| 2N55551ZL1G | $\begin{gathered} \text { TO-92 } \\ \text { (Pb-Free) } \end{gathered}$ |  |

$\dagger$ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## PACKAGE DIMENSIONS

## TO-92 (TO-226)

CASE 29-11
ISSUE AM


STRAIGHT LEAD
BULK PACK
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|  | INCHES |  | MILLIMETERS |  |
| :---: | :---: | ---: | ---: | ---: |
| DIM | MIN | MAX | MIN | MAX |
| A | 0.175 | 0.205 | 4.45 | 5.20 |
| B | 0.170 | 0.210 | 4.32 | 5.33 |
| C | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.021 | 0.407 | 0.533 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| H | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | --- | 12.70 | --- |
| L | 0.250 | --- | 6.35 | --- |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| P | --- | 0.100 | --- | 2.54 |
| R | 0.115 | --- | 2.93 | --- |
| V | 0.135 | --- | 3.43 | --- |



BENT LEAD
TAPE \& REEL AMMO PACK


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

|  | MILLIMETERS |  |
| :---: | :---: | :---: |
| DIM | MIN | MAX |
| $\mathbf{A}$ | 4.45 | 5.20 |
| $\mathbf{B}$ | 4.32 | 5.33 |
| $\mathbf{C}$ | 3.18 | 4.19 |
| $\mathbf{D}$ | 0.40 | 0.54 |
| $\mathbf{G}$ | 2.40 | 2.80 |
| $\mathbf{J}$ | 0.39 | 0.50 |
| $\mathbf{K}$ | 12.70 | --- |
| $\mathbf{N}$ | 2.04 |  |
| $\mathbf{P}$ | 1.50 | 4.00 |
| $\mathbf{R}$ | 2.93 | --- |
| $\mathbf{V}$ | 3.43 | --- |

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## PUBLICATION ORDERING INFORMATION

## LITERATURE FULFILLMENT

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